

EM Noise Mitigation in Circuit Boards and Cavities

Faculty (UMD): Omar M. Ramahi, Neil Goldsman and John Rodgers
Visiting Professors (Finland): Fad Seydou
Graduate Students (UMD): Xin Wu, Lin Li, Baharak Mohajeriravani,
and Shahrooz Shahparnia

Mechanical Engineering Department,
Electrical and Computer Engineering Department and
CALCE Electronic Products and Systems Center
University of Maryland, College Park, MD

Microwave Effects and Chaos in 21st Century Analog & Digital Electronics

AFOSR MURI

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Rockville, MD



[Completed]

Previous Work and Recent Work

□ Developing 3-dimensional full-wave predictive tools for cavity Resonance and S Parameters [Completed]
 □ Developing fast predictive modeling tools for PCB analysis [Completed]
 □ Using lossy material coating to reduce aperture radiation [Completed]
 □ Reduction of coupling between cavities using high-impedance surfaces

Previous Work and Recent Work

 Reducing noise in printed circuit boards using high impedance surface

Previous:

- 1. Concept development
- 2. Experimental verification
- 3. Wideband extension

New:

- 1. Accurate wideband prediction
- 2. Wideband extension using advanced materials
- 3. Band gap design
- 4. Miniaturization



Reduce switching and other noise in Printed Circuit Boards

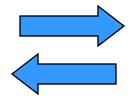


Importance of PCBs

- Everything will be printable!
- Cost
- Compactness

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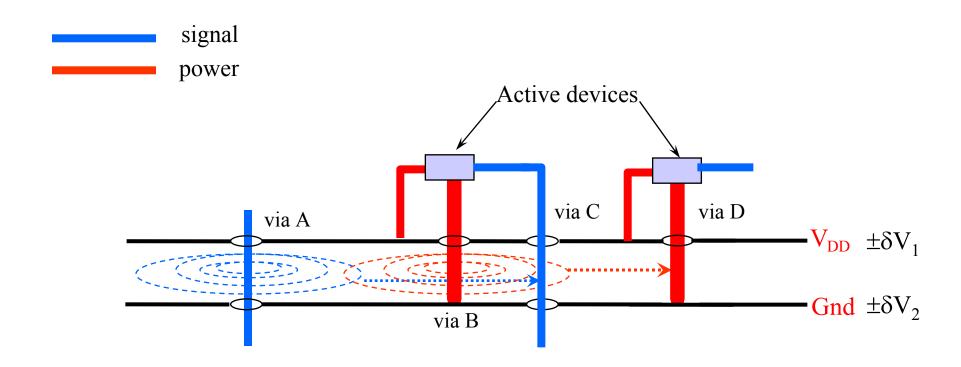
PCB not radiating



immune from external radiation



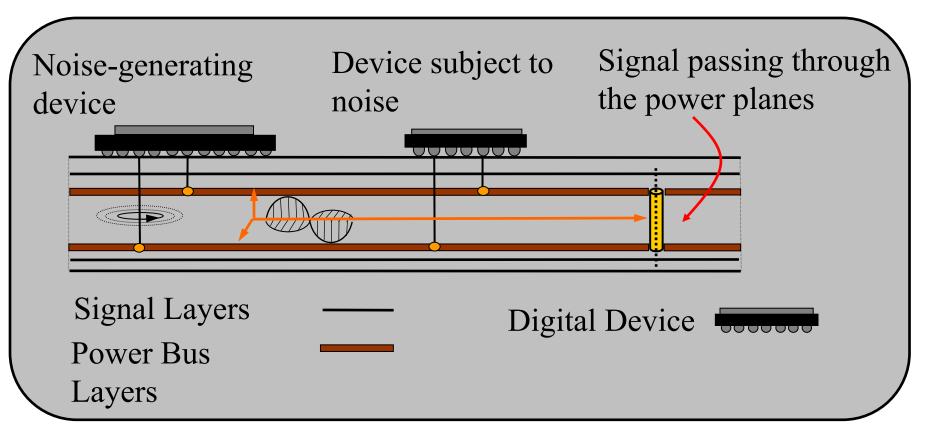
EM Noise in PCB





Motivation

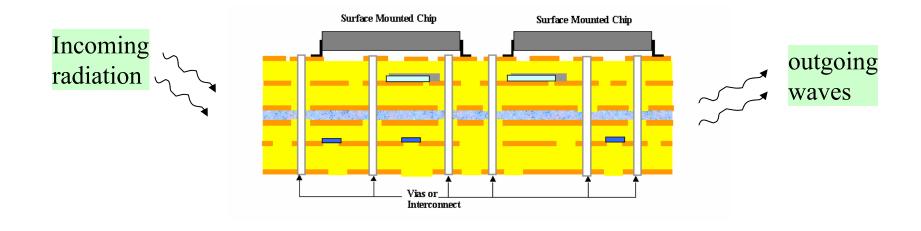
Problem: Switching noise



Need to do something for mitigation of noise beyond ~ 500MHz



Coupling to Sensitive Devices in a Multi-Layer Stack up

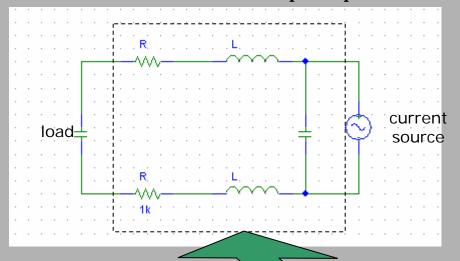


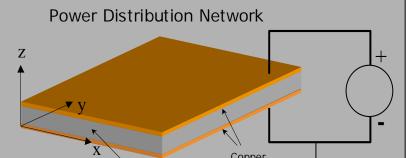


Problem and Classical Solutions

•Interconnect and Board Inductance

R-L circuit model for the power plane



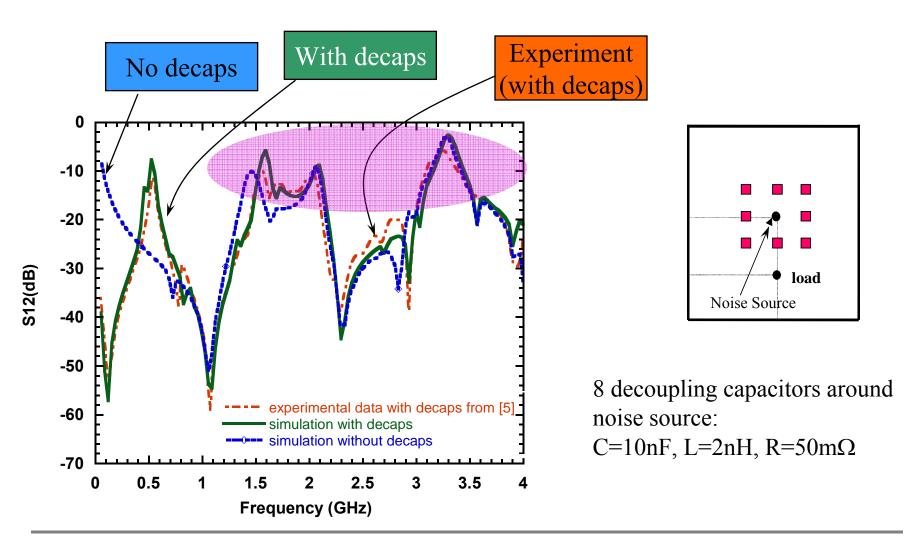


Voltage drop between two points on the board depends on the inductance, L, and resistance R.

$$V_{L} = L_{\it eff} \; rac{\partial i}{\partial t}$$



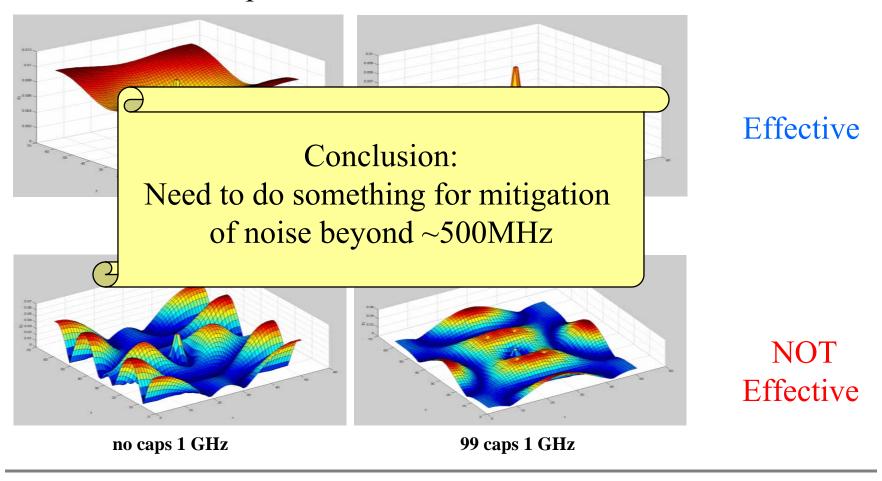
Decoupling Capacitors around Noise Source





Classical Methods: Ineffective at Microwave Frequencies

•Effect of Capacitors Placement at 200MHz and 1GHz

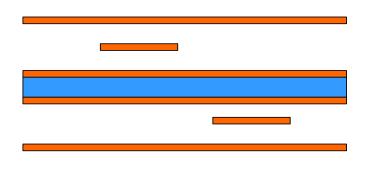


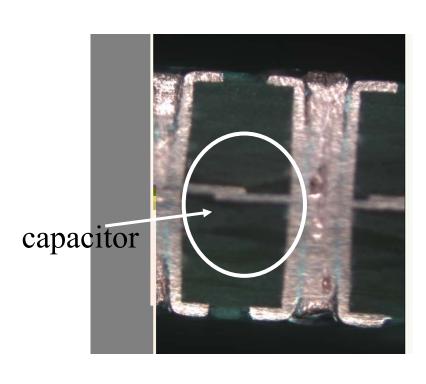


Possible Solutions

Embedded Capacitors

Embedded *Capacitance*



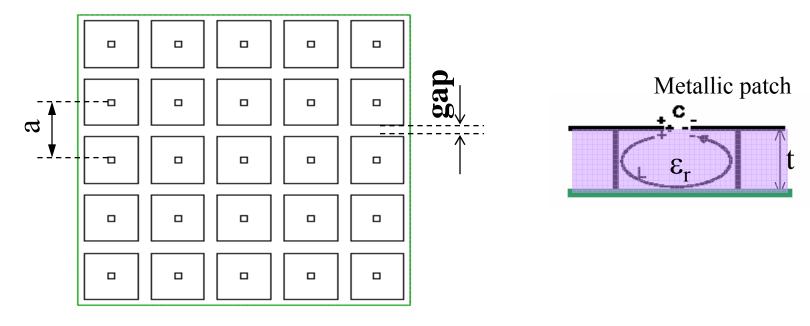




Electromagnetic Band Gap Structures for switching noise mitigation



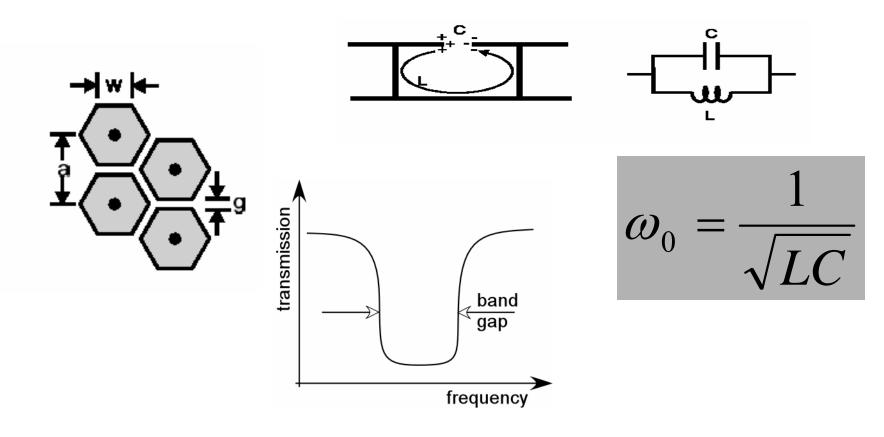
Electromagnetic Band Gap Structures (EBG) for "Surface" Wave Suppression



Top view of HIS with square patches

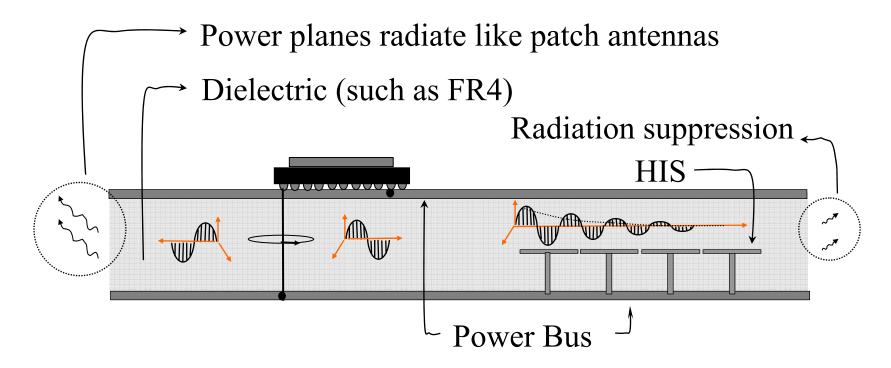


Interpretation: EBG as a Series of Parallel LC Resonators





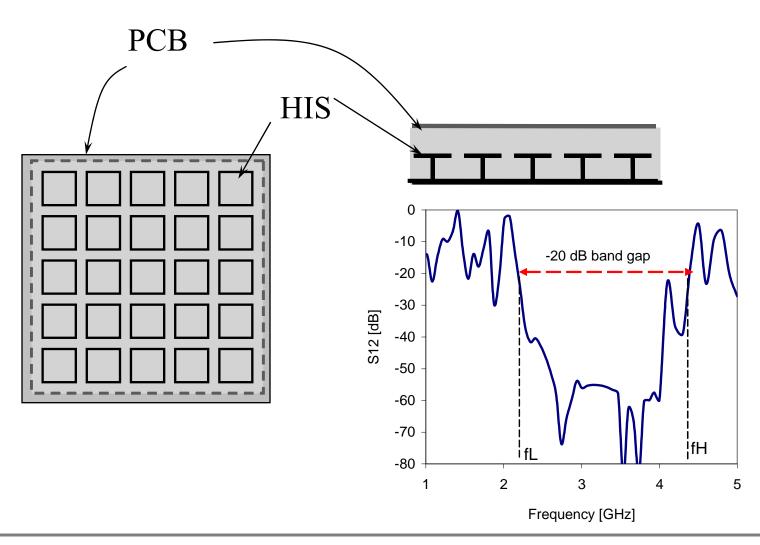
Suppression Mechanism



• Both propagation and emission from the board are suppressed with the employment of EEBG/EHIS structures.



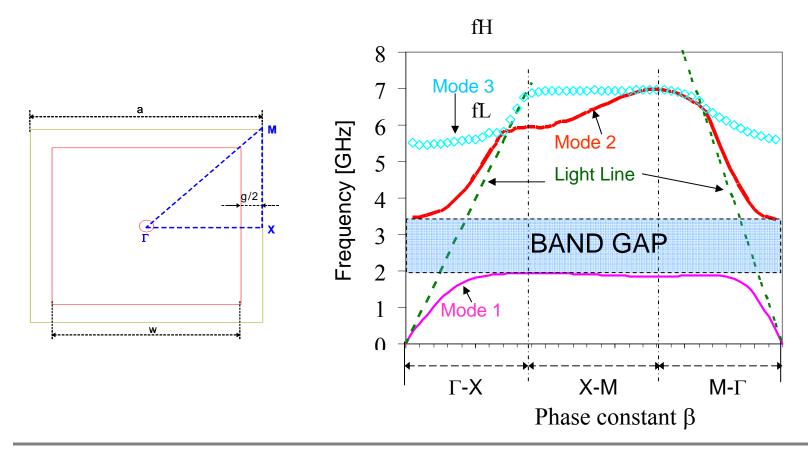
Power Plane with Embedded HIS





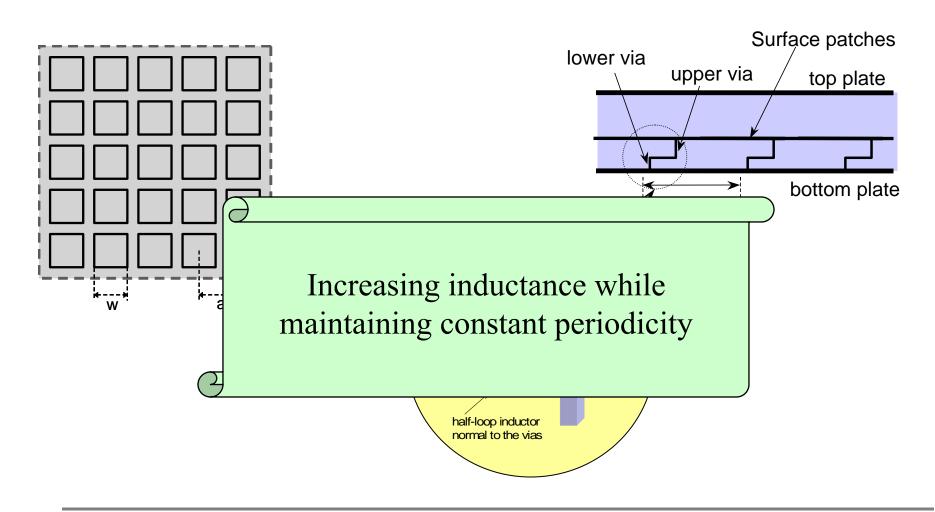
Stop Band Prediction

Analysis of a unit cell provides eigenmode solutions for Maxwell's equations



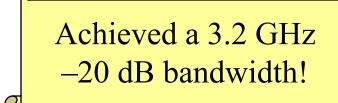


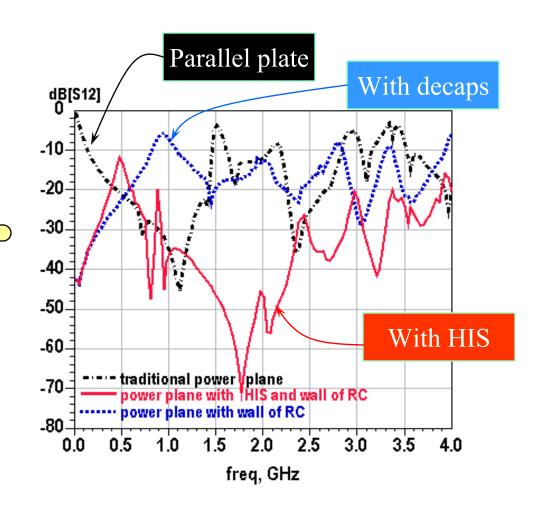
Widening the Gap: Concept: Vertical Integration





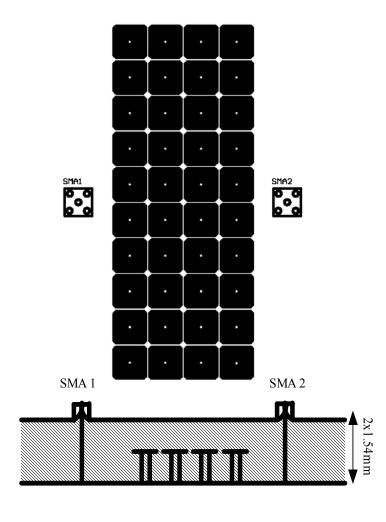
EBG Inductance-Enhanced Power Planes

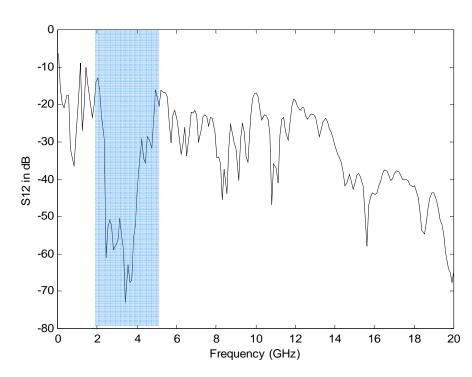






Experimental Validation



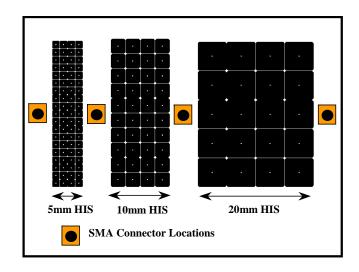


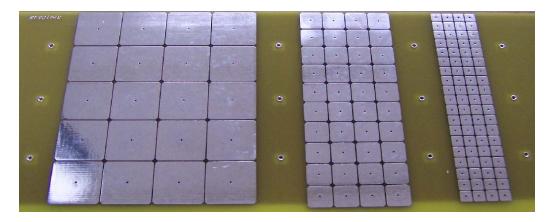
HIS: period a = 10mm and gap g = 0.4 mm



Widening the Gap Concept: Cascading

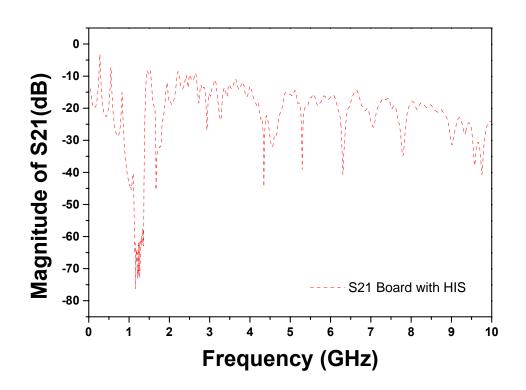
Concept: cascaded filter design





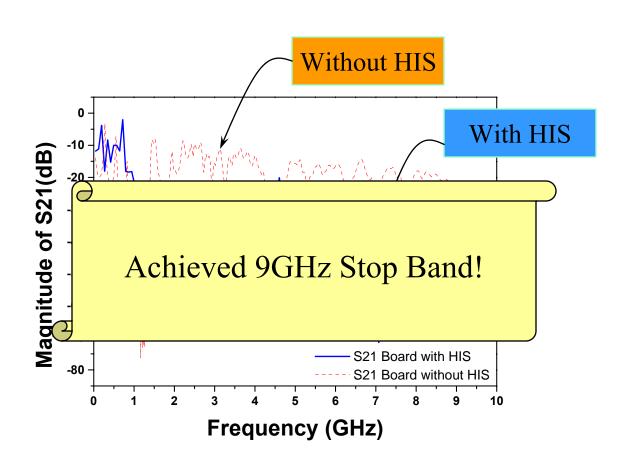


Experimental Validation



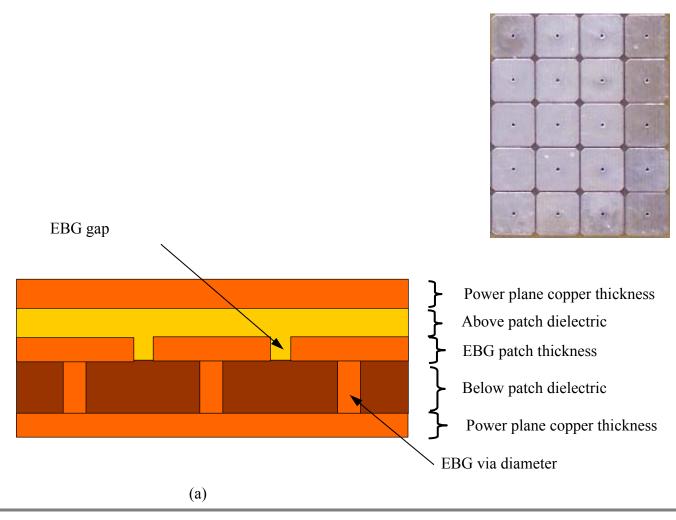


Experimental Validation



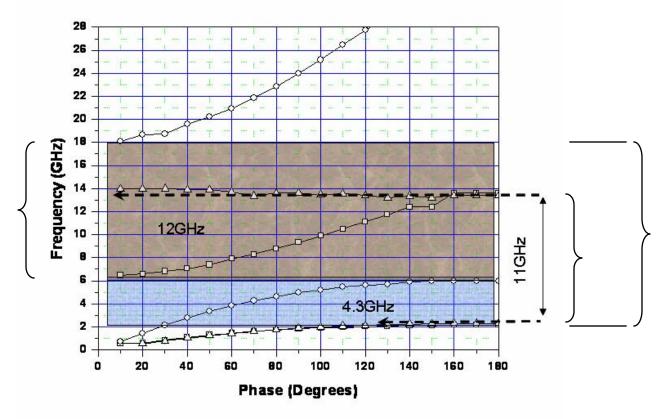


Widening the Gap Concept: High Permittivity Material





Numerical Validation



Dispersion diagram for entries 5, 7 and 8 in Table I. Entry 5 can achieve and ultra-wide band gap (11 GHz) using high-dielectric material. Cascading entries 7 and 8 can also achieve a wide-band region (16 GHz) but at a far lower cost.



Numerical Validation

Entry Number	Patch size (mm)	Above patch ε _r	Below patch ε _r	Above patch th. (um)	Below patch th. (um)	Patch th. (um)	Gap size (um)	Via diameter (um)	$\mathbf{f_l}$	$\mathbf{f_h}$
1	10x10	4.1	4.1	1540	1540	0	400	800	2.13	4.03
2	10x10	8.2	4.1	1540	1540	0	400	800	1.6	3.71
3	10x10	12.3	4.1	1540	1540	0	400	800	1.35	3.12
4	10x10	16.4	4.1	1540	1540	0	400	800	1.22	2.87
5	2x2	30	4.1	16	100	0	200	125	2.3	13.1
6	2x2	30	4.1	16	100	35	200	125	2.28	13.2
7	2x2	4.1	4.1	16	100	0	200	125	5.96	18.1
8	5x5	4.1	4.1	16	100	0	200	125	2.17	6.46
9	5x5	16.4	4.1	16	100	0	200	125	1.11	6.44

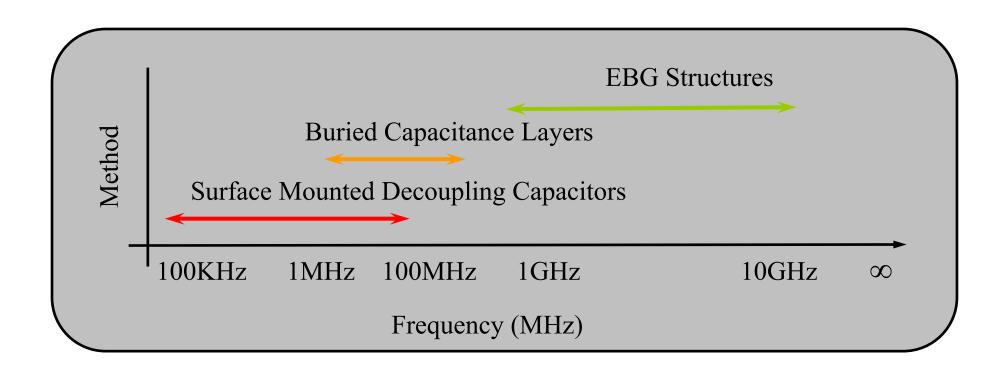


Experimental Validation

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Achievements

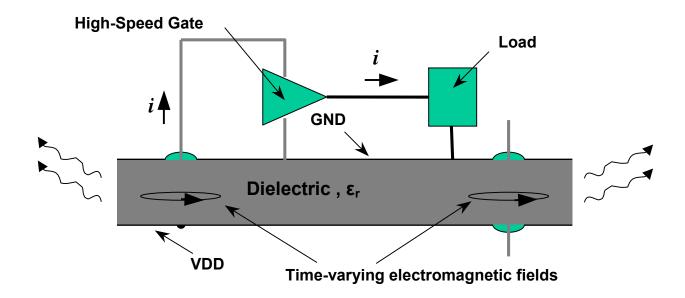




Part II: EMI Reduction from PCBs (Interference and Immunity)



External Radiation from PCBs



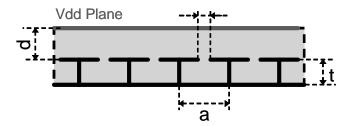


EMI Reduction through EBGs

Concept:

Same as switching noise mitigation...

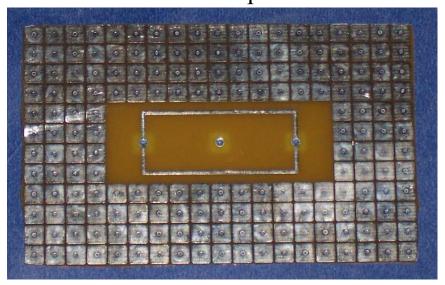
If waves don't travel within the PCB, they will not radiate!

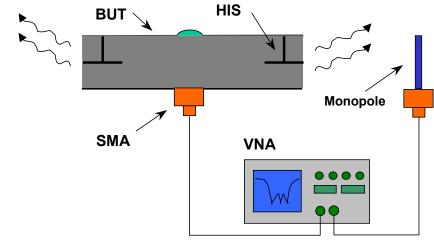




EMI Measurement Setup

5mm x 5mm patches

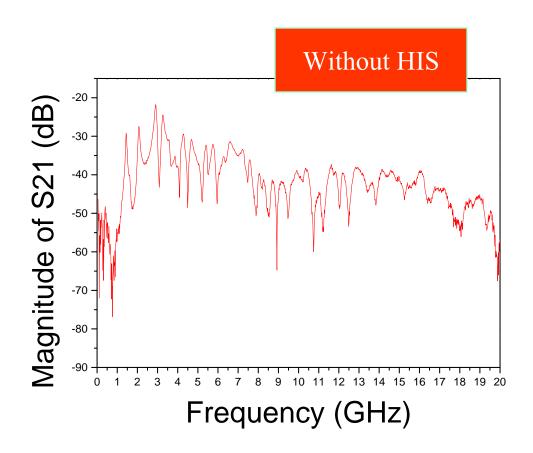




10cm x 6.5cm board

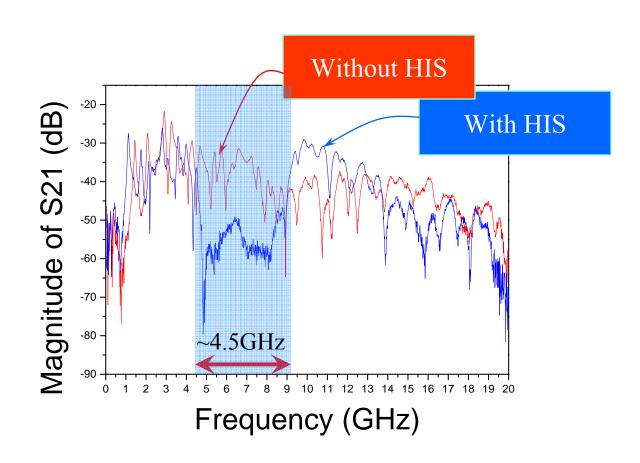


Effect of HIS on EMI





Effect of HIS on EMI

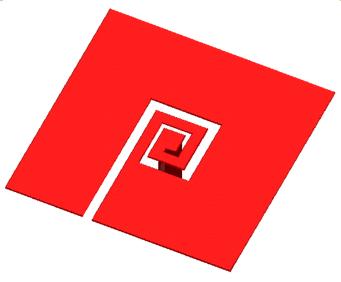




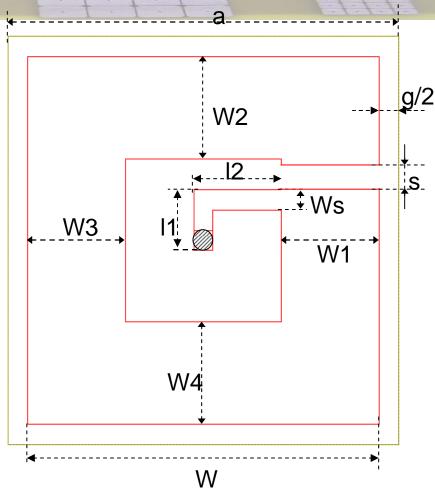
Part III: Multiband EBG Design



Novel single-layer inductance-enhanced EBG



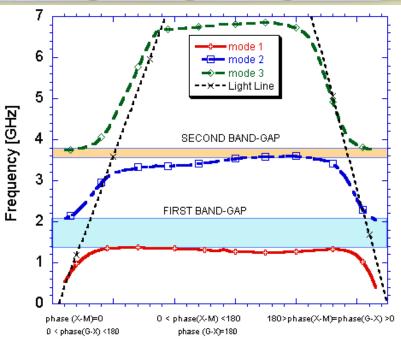
- Variable line width inductor used to replace patch of standard HIS
- Inductance of spiral adds in series to that of via
- High fringing capacitance through fat outer lines
- Additional design variables: number of turns, starting inner diameter, trace width

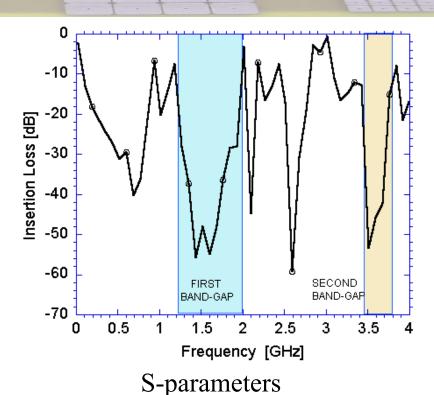


implementation for a period of 10 mm



Electrical performance of novel EBG in parallel-plate environment





Dispersion diagram

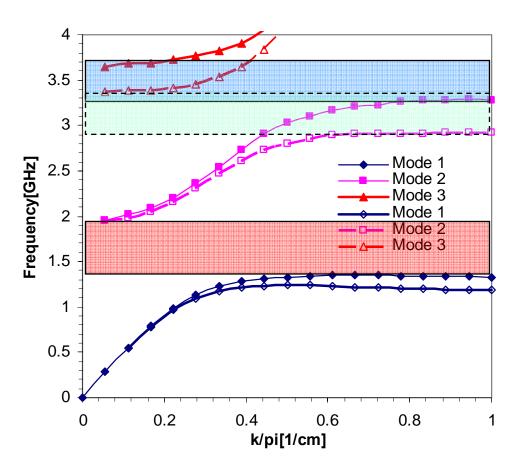
s=0.4 mm, W=9 mm, g=1 mm, a=10 mm, W1=3.5, W2=W3=W4=2.5 mm, l1=1.5 mm, l2=2 mm, Ws=0.5 mm

- Existence of two band-gaps
- Multiband noise mitigation possible

• Type of modes also analyzed by looking at field plots at different phase constant



Upper bandgap tuning using spacing



Spacing (gap) is reduced from 1mm (filled symbols) to 0.4 mm (empty symbols)

Upper band:

Moves towards lower frequencies with slight variation in the bandwidth

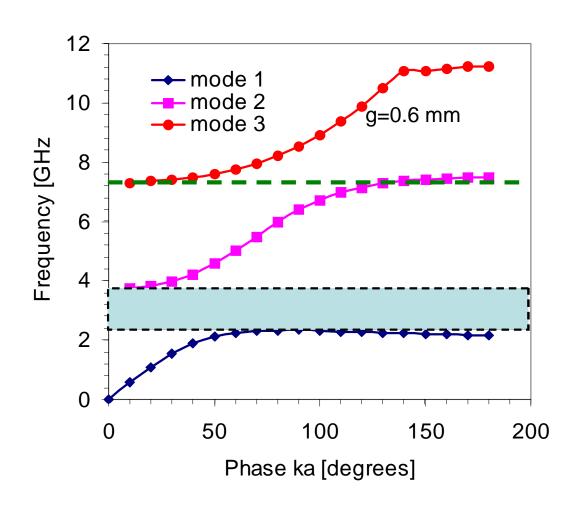
Lower band:

- Lower edge slightly affected
- Change can be compensated through variation in the spiral inductor geometry or period

This indicates that the two bands can be tuned independently



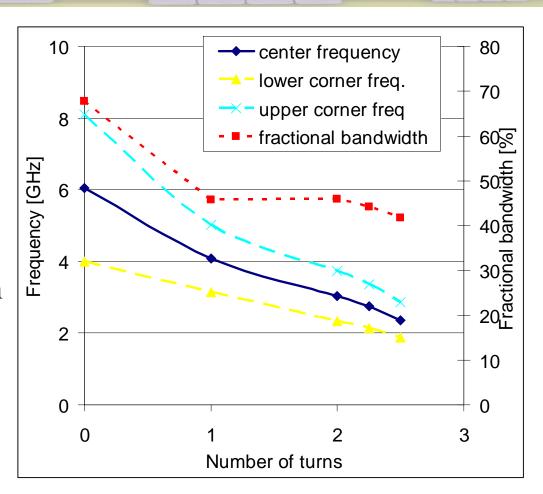
Second band-gap disappearance in a structure with smaller periods





Effect of number of turns on first band-gap

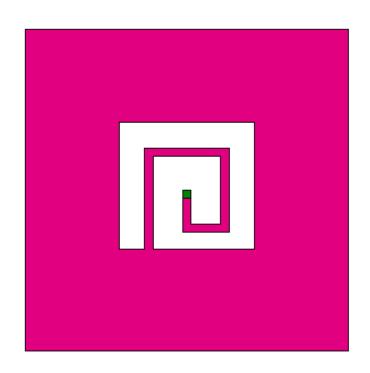
- Physical dimensions: a=5mm, g=0.6mm, t=d=1.54mm
- Band-gap shift to lower frequency, when traditional HIS replaced with novel EBG
- Band-gap lowering with increase in number of turns
- Fractional bandwidth > 40% at 2GHz



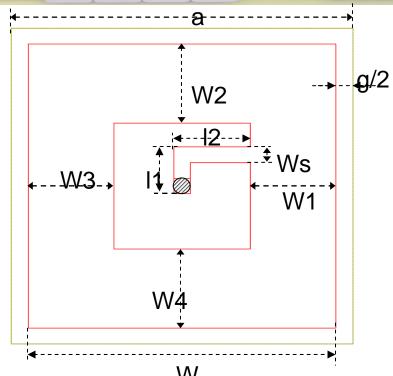
Note: N=0 corresponds to standard HIS



"Complementary" Structure



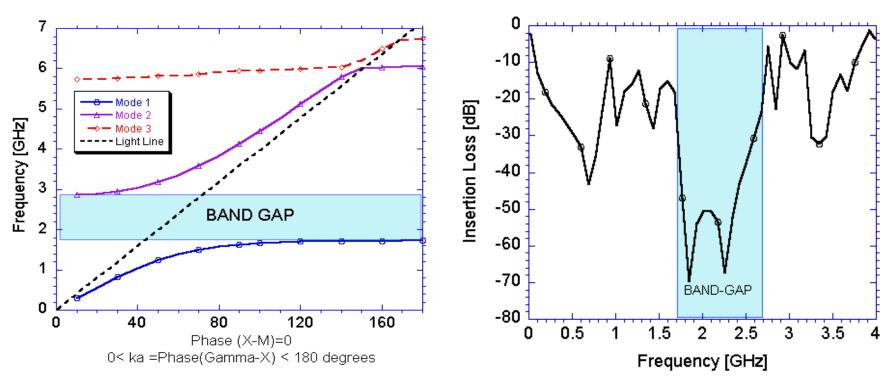
concept



Practical implementation for large period (a=10mm)



EBG using spiral with outer loop closed as patch: simulation results



W=9 mm, g=1 mm, a=10 mm, W1=3.5, W2=W3=W4=2.5 mm, l1=1.5 mm, l2=2 mm, Ws=0.5 mm.

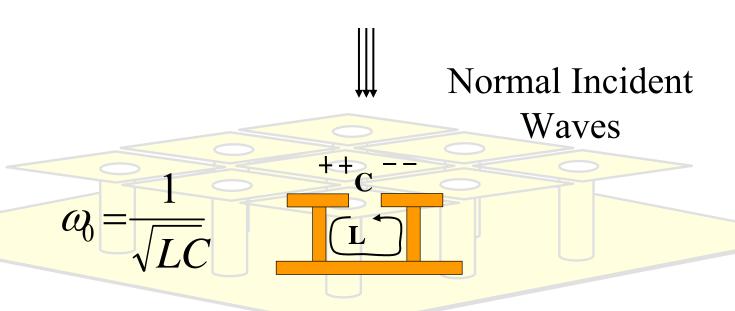
 Band-gap region at lower frequencies compared to power plane with standard HIS

- The whole structure, acts as a band-stop filter by suppressing surface waves within a predictable range of frequencies. *It also suppresses waves supporting surface currents*
- This frequency range is a function of the geometrical features of the structure (such as periodicity, patch size, gap size, via diameter, via length and also board thickness) as well as the dielectric material used in the printed circuit board as substrate.



Part III: Accurate Band Gap Prediction

Electromagnetic Bandgap Structures: Lumped Element Perspective

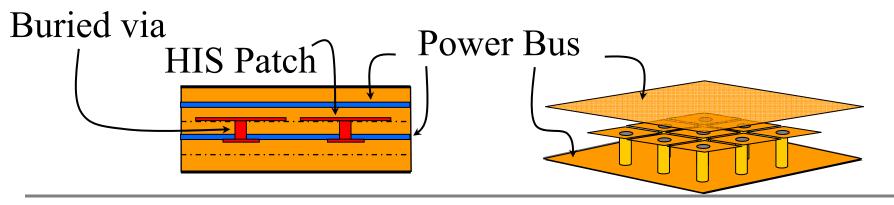




Design and Fabrication

• Design and simulation of EEBG structures is followed by fabrication using a commercial PCB process with FR-4 as dielectric.





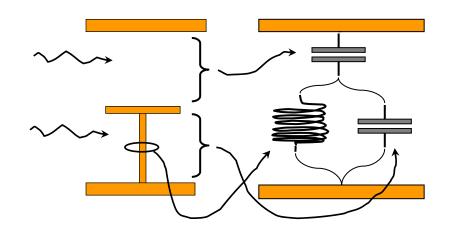
Need for Simple and Accurate Models

- Full wave simulations are slow and costly
- It is costly and not feasible to do trial and error experiments
- Engineers like to have initial but accurate estimations of the resulting bandgap by doing a couple of calculations



Fast and Simple Design Technique

Lateral view of a single cell



 Physics-based circuit modeling

$$f_{res} = \frac{1}{2\pi\sqrt{L (C_1 + C_2)}}$$

HIS via (L value: approximate methods)

Plate-to-Patch Capacitance $(C_1 = \varepsilon_r \varepsilon_0 S_p^2 / H_v)$

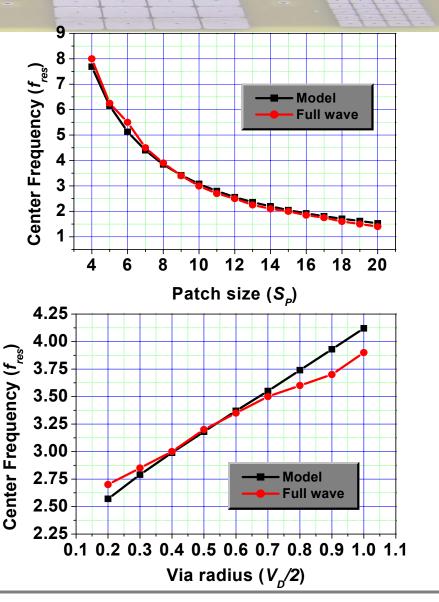
Patch-to-Plate Capacitance ($C_2 = \varepsilon_r \varepsilon_0 S_p^2 / H_v$)



Accuracy of the Model

• Accuracy of the model while the patch sizes changes (C₁ and C₂ change)

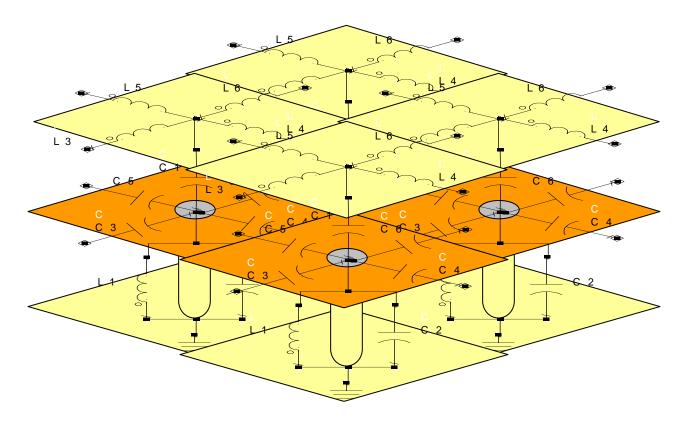
• Accuracy of the model while the via radius changes (L changes)





3D Model

• EEBG cell model integrated in a macro-model of power/ground planes.



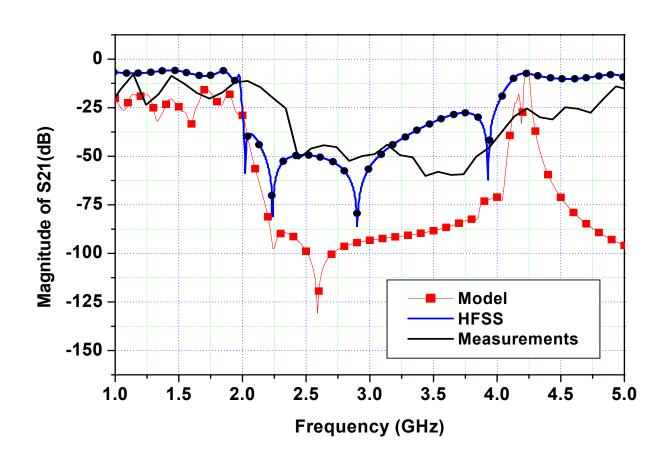


Why the circuit model?

Reduce printed circuit board simulation time from HOURS to seconds!



Numerical and Experimental Results





Conclusions

- Provided accurate EBG-embedded PCB models
- Introduced multi-band EBG design concepts
- •Introduced three different concepts for wideband applications



Future Work

Miniaturization!